

NCT65

Remote Trip Point Temperature Sensor with Overtemperature Shutdown

Description

The NCT65 is a low power temperature monitor housed in an MSOP8 package. It monitors the temperature of a remote thermal diode. The resulting temperature is then compared with fixed $\overline{\text{THERM}}$ limits (70°C and 85°C) and if the resulting temperature is greater than these limits, the open-drain $\overline{\text{THERM1}}$ and $\overline{\text{THERM2}}$ pins are asserted. To prevent constant assertion and deassertion of the $\overline{\text{THERM}}$ outputs the NCT65 has 5°C of hysteresis.

The NCT65 supply range is 2.8 V to 3.6 V and features low supply current making it suitable for portable applications.

Features

- Remote Temperature Sensor
- 0°C – 85°C Measurement Range
- Two Overtemperature $\overline{\text{THERM}}$ Shutdown Pins
- $\overline{\text{THERM1}}$ Trip Point = 70°C, $\overline{\text{THERM2}}$ Trip Point = 85°C
- Low Power Operation
- MSOP Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Smart Phones
- Consumer Electronics
- Embedded Systems
- Smart Batteries
- Desktop and Notebook Computers



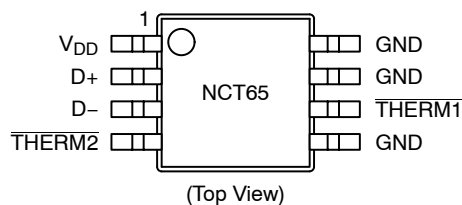
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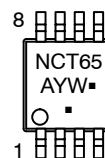


MSOP-8
RM SUFFIX
CASE 846AB

PIN CONNECTIONS



MARKING DIAGRAM



NCT65 = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NCT65DMR2G	MSOP-8 (Pb-Free)	3,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NCT65

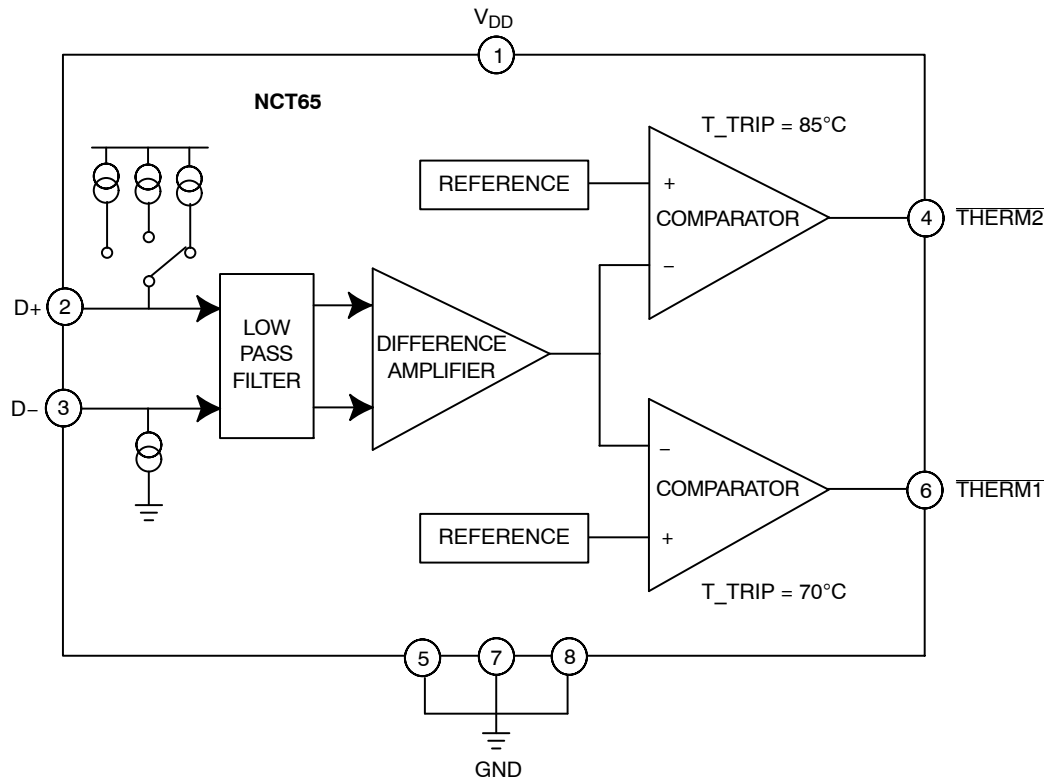


Figure 1. Functional Block Diagram

Table 1. PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	V _{DD}	Positive Supply Voltage. 2.8 V to 3.6 V.
2	D+	Positive Connection for Remote Temperature Sensor.
3	D-	Negative Connection for Remote Temperature Sensor.
4	THERM2	Active-low Open-drain Over-temperature Output Pin; Needs a Pull-up Resistor.
5	GND	Power Supply Ground.
6	THERM1	Active-low Open-drain Over-temperature Output Pin; Needs a Pull-up Resistor.
7	GND	Power Supply Ground.
8	GND	Power Supply Ground.

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Table 2. ABSOLUTE MAXIMUM RATINGS (Note 1)

Parameter	Rating	Unit
Positive Supply Voltage (V_{DD}) to GND	-0.3, +0.3	V
D+	-0.3 to $V_{DD} + 0.3$	V
D- to GND	-0.3 to +3.6	V
THERM	-0.3 to +3.6	V
Input Current, THERM	-1, +50	mA
Input Current, D-	± 1	mA
Maximum Junction Temperature	150	°C
Storage Temperature Range	-65 to 160	°C
ESD Capability, Human Body Model (Note 2)	1,500	V
ESD Capability, Machine Model (Note 2)	150	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- This device series incorporates ESD protection and is tested by the following methods:
ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
- Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

Table 3. THERMAL CHARACTERISTICS (Note 3)

Rating	Symbol	Value	Unit
Thermal Characteristics, MSOP (Note 4) Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	142	°C/W

- Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- As measured using a copper heat spreading area of 650 mm² (or 1 in²), of 1 oz copper thickness.

Table 4. OPERATING RANGES (Note 5)

Rating	Symbol	Min	Max	Unit
Operating Input Voltage	V_{IN}	2.8	3.6	V
Operating Ambient Temperature Range	T_A	-40	125	°C

- Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

Table 5. ELECTRICAL CHARACTERISTICS

($T_A = T_{MIN}$ to T_{MAX} , $V_{DD} = 2.8$ V to 3.6 V. All specifications for -40°C to +125°C, unless otherwise noted.)

Parameter	Test Conditions	Min	Typ	Max	Unit
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POWER SUPPLY

Supply Voltage V_{DD}		2.8	3.3	3.6	V
Average Operating Supply Current, I_{DD}		-	-	1.15	mA
Undervoltage Lockout Threshold		-	2.55	-	V

TRIP POINT ACCURACY

Trip Point Accuracy at $V_{DD} = 2.8$ V to 3.6 V	$T_A = 0^\circ\text{C}$ to +70°C $T_A = 0^\circ\text{C}$ to +85°C	-	-	± 1 ± 1.5	°C
Response Time	Temperature Measurement to THERM Assertion	-	40	52	ms

OPEN DRAIN OUTPUT (THERM)

Output Low Voltage, V_{OL}	$I_{OL} = -6.0$ mA	-	-	0.4	V
High Output Leakage Current, I_{OH}	$V_{OUT} = V_{DD}$	-	0.1	1.0	μA
Hysteresis	The temperature must drop by this amount below the THERM trippoints before the pins will de-assert	-	5	-	°C

Theory of Operation

The NCT65 is a remote trip point temperature sensor for use in a wide variety of applications from smart phones to embedded systems. The remote temperature is measured by the NCT65 and then compared with a fixed limit set by the internal device reference. The limit for the $\overline{\text{THERM1}}$ pin is 70°C and the limit for the $\overline{\text{THERM2}}$ pin is 85°C. If either the remote temperature exceeds the defined limits the open drain $\overline{\text{THERM}}$ pins are asserted low. Each $\overline{\text{THERM}}$ pin self clears when the temperature drops 5°C below the $\overline{\text{THERM}}$ limit. This is to prevent $\overline{\text{THERM}}$ jitter, where the temperature hovers around the $\overline{\text{THERM}}$ limit.

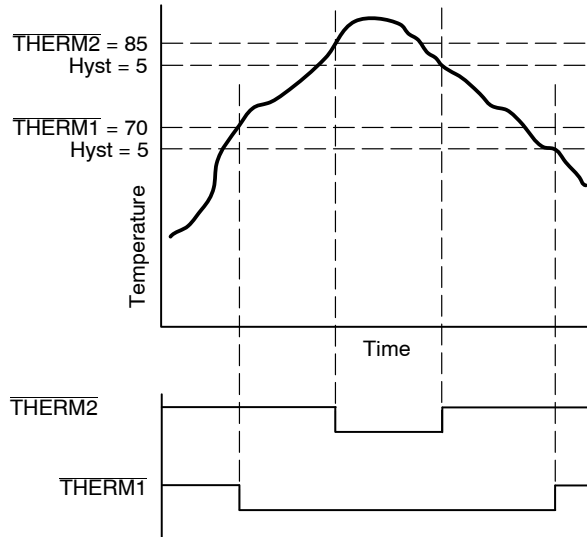


Figure 2. Trippoints

Measurement Method

A simple method of measuring temperature is to exploit the negative temperature coefficient of a diode, or the base-emitter voltage of a transistor, operated at constant current. Unfortunately, this technique requires calibration to null out the effect of the absolute value of V_{BE} , which varies from device to device.

The technique used in the NCT65 is to measure the change in V_{BE} when the device is operated at three different currents.

This is given by:

$$\Delta V_{BE} = (n_f) \frac{kT}{q} \times \ln(N) \quad (\text{eq. 1})$$

Where:

- k is Boltzmann's constant (1.38×10^{-23}).
- q is the charge on the electron (1.6×10^{-19} Coulombs).
- T is the absolute temperature in Kelvins.
- N is the ratio of the two currents.
- n_f is the ideality factor of the thermal diode.

The NCT65 is trimmed for an ideality factor of 1.008.

To prevent ground noise interfering with the measurement, the more negative terminal of the sensor is not referenced to ground but is biased above ground by an internal diode at the D- input. If the sensor is operating in a noisy environment an optional filter can be added. Its value should be no more than 1,000 pF. See the Layout Considerations section for more information on C1.

To measure ΔV_{BE} , the operating current through the sensor is switched among three related currents.

$N1 \times I$ and $N2 \times I$ are different multiples of the current, I. The currents through the temperature diode are switched between I and $N1 \times I$, giving ΔV_{BE1} ; and then between I and $N2 \times I$, giving ΔV_{BE2} . The temperature is then calculated using the two ΔV_{BE} measurements. This method also cancels the effect of any series resistance on the temperature measurement. The resulting waveform is passed through a 65 kHz low-pass filter to remove noise, and then to a chopper-stabilized amplifier that performs the functions of amplification and rectification of the waveform to produce a dc voltage proportional to ΔV_{BE} . This voltage is input into two comparators with a reference voltage. If the voltage exceeds the reference voltage then the $\overline{\text{THERM}}$ output asserts low.

Applications Information

Noise Filtering

For temperature sensors operating in noisy environments, the industry standard practice was to place a capacitor across the D+ and D- pins to help combat the effects of noise. However, large capacitances affect the accuracy of the temperature measurement, leading to a recommended maximum capacitor value of 1,000 pF. Although this capacitor reduces the noise, it does not eliminate it, making it difficult to use the sensor in a very noisy environment.

The NCT65 has a major advantage over other devices when it comes to eliminating the effects of noise on the external sensor. The series resistance cancellation feature allows a filter to be constructed between the external temperature sensor and the part. The effect of any filter resistance seen in series with the remote sensor is automatically cancelled from the temperature result.

The construction of a filter allows the NCT65 and the remote temperature sensor to operate in noisy environments.

The figure below shows a low-pass R-C-R filter, where $R = 100 \Omega$ and $C = 1 \text{ nF}$. This filtering reduces both common-mode and differential noise.

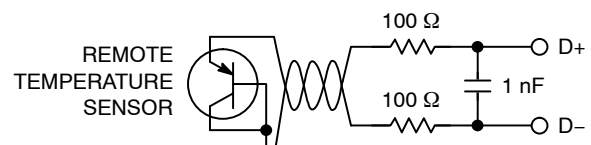


Figure 3. Filter between Remote Sensor and Factors Affecting Diode Accuracy

Remote Sensing Diode

The NCT65 is designed to work with substrate transistors built into processors or with discrete transistors. Substrate transistors are generally PNP types with the collector connected to the substrate. Discrete types are either PNP or NPN transistors connected as diodes (base-short to collector). If an NPN transistor is used, the collector and base are connected to D+ and the emitter to D-. If a PNP transistor is used, the collector and base are connected to D- and the emitter to D+.

Layout Considerations

Digital boards can be electrically noisy environments, and the NCT65 is measuring very small voltages from the remote sensor, so care must be taken to minimize noise induced at the sensor inputs. Take the following precautions:

- Place the NCT65 as close as possible to the remote sensing diode. Provided that the worst noise sources, that is, clock generators, data/address busses etc., are avoided, this distance can be 4 to 8 inches.
- Route the D+ and D- tracks close together, in parallel, with grounded guard tracks on each side. To minimize inductance and reduce noise pickup, a 5 mil track width and spacing is recommended. Provide a ground plane under the tracks, if possible.
- Place a 0.1 μ F bypass capacitor close to the V_{DD} pin. In extremely noisy environments, place an input filter

capacitor across D+ and D- close to the NCT65. This capacitance can effect the temperature measurement, so ensure that any capacitance seen at D+ and D- is, at maximum, 1,000 pF. This maximum value includes the filter capacitance, plus any cable or stray capacitance between the pins and the sensor diode.



Figure 4. Typical Arrangement of Signal Tracks

Application Circuit

The figure below shows a typical application circuit for the NCT65, using an embedded transistor on a GPU to measure the temperature. The THERM1 pin can be used to alert the system and throttle the GPU. The THERM2 pin can be used to shutdown the system if necessary. Both pins require pullup resistors to V_{DD} or an alternative supply (up to 3.6 V).

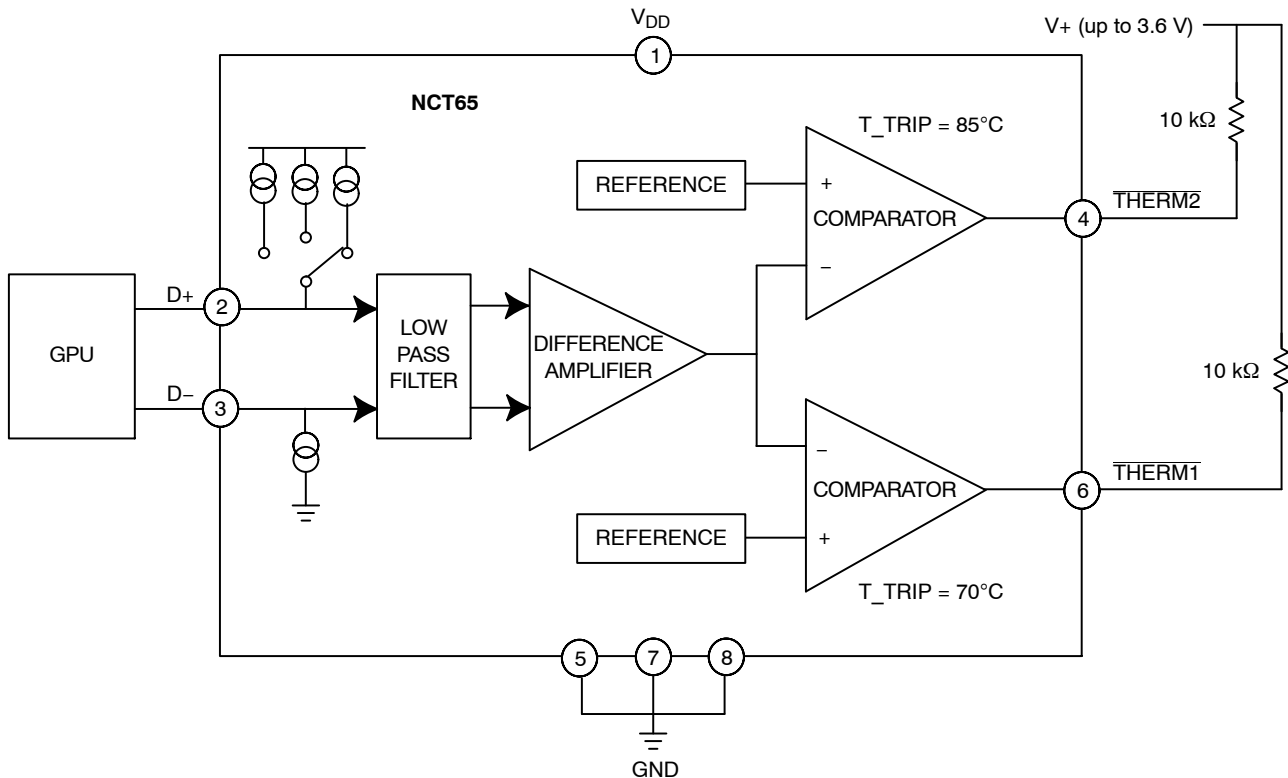
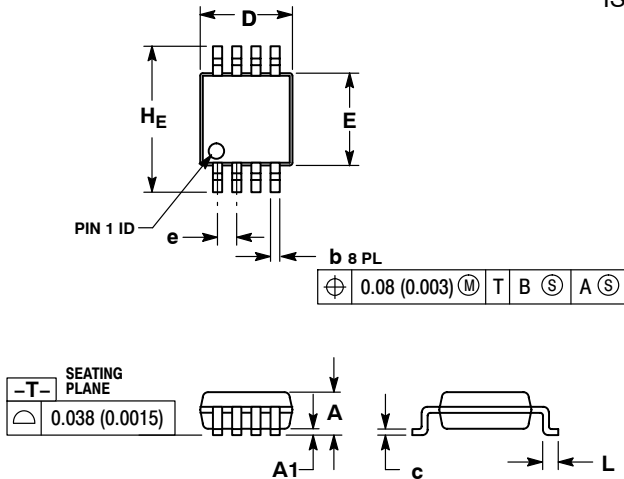


Figure 5. Typical Configuration Block Diagram

NCT65

PACKAGE DIMENSIONS

MSOP8 CASE 846AB-01 ISSUE O

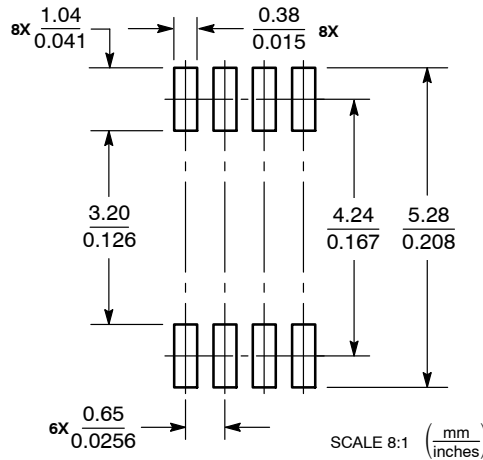


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. 846A-01 OBSOLETE, NEW STANDARD 846A-02.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	—	—	1.10	—	—	0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
c	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
e	0.65 BSC			0.026 BSC		
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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